



Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at
www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

FSL137MRIN

Green-Mode Fairchild Power Switch (FPS™)

Features

- Advanced Soft Burst Mode for Low Standby Power and Low Audible Noise
- Random Frequency Fluctuation (RFF) for Low EMI
- Under 50 mW Standby Power Consumption at 265 V_{AC}, No-load Condition with Burst Mode
- Pulse-by-Pulse Current Limit
- Overload Protection (OLP), Over-Voltage Protection (OVP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD) with Hysteresis, Output-Short Protection (OSP), and Under-Voltage Lockout (UVLO) with Hysteresis, Line Over-Voltage Protection (LOVP)
- Low Operating Current (0.4 mA) in Burst Mode
- Internal Startup Circuit
- Internal High-Voltage SenseFET: 700 V
- Built-in Soft-Start: 15 ms
- Auto-Restart Mode

Applications

- Power Supply for Home Appliances, LCD Monitors, STBs, and DVD Players

Description

The FSL137MRIN is an integrated Pulse Width Modulation (PWM) controller and SenseFET specifically designed for offline Switched Mode Power Supplies (SMPS) with minimal external components. The PWM controller includes an integrated fixed-frequency oscillator, Line Over-Voltage Protection (LOVP), Under-Voltage Lockout (UVLO), Leading-Edge Blanking (LEB), optimized gate driver, internal soft-start, temperature-compensated precise current sources for loop compensation, and self-protection circuitry.

Compared with a discrete MOSFET and PWM controller solution, the FSL137MRIN reduces total cost, component count, size, and weight; while simultaneously increasing efficiency, productivity, and system reliability. This device provides a basic platform suited for cost-effective design of flyback converters.

Ordering Information

Part Number	Package ⁽¹⁾	Operating Junction Temperature	Current Limit (Typ.)	R _{DS(ON)} (Max.)	Output Power Table ⁽²⁾			
					230 V _{AC} ±15%		85-265 V _{AC}	
					Adapter ⁽³⁾	Open Frame ⁽⁴⁾	Adapter ⁽³⁾	Open Frame ⁽⁴⁾
FSL137MRIN	8-DIP	-40°C ~ +125°C	1.3 A	4.75 Ω	25 W	30 W	15 W	20 W

Notes:

1. Lead-free package per JEDEC J-STD-020B.
2. The junction temperature can limit the maximum output power.
3. Typical continuous power in a non-ventilated enclosed adapter measured at 50°C ambient temperature.
4. Maximum practical continuous power in an open-frame design at 50°C ambient temperatures.

Pin Configuration

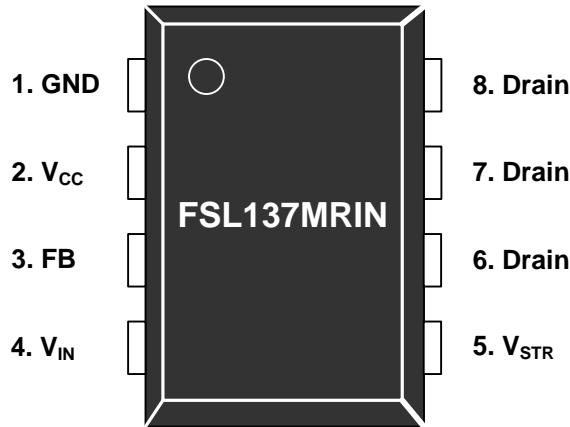


Figure 3. Pin Assignments (Top View)

Pin Definitions

Pin #	Name	Description
1	GND	Ground. This pin is the control ground and the SenseFET source.
2	V _{CC}	Power Supply. This pin is the positive supply input, which provides the internal operating current for both startup and steady-state operation.
3	FB	Feedback. This pin is internally connected to the inverting input of the PWM comparator. The collector of an opto-coupler is typically tied to this pin. For stable operation, a capacitor should be placed between this pin and GND. If the voltage of this pin reaches 7 V, the overload protection triggers, which shuts down the FPS.
4	V _{IN}	Line Over-Voltage Input. This is the input pin of line voltage. The voltage, which is divided by resistors, is the input of this pin. If this pin voltage is higher than V _{INH} voltage, the LOVP triggers, which shuts down the FPS. Do not leave this pin floating. If LOVP is not used, this pin should be directly connected to GND.
5	V _{STR}	Startup. This pin is connected directly, or through a resistor, to the high-voltage DC link. At startup, the internal high-voltage current source supplies internal bias and charges the external capacitor connected to the V _{CC} pin. Once V _{CC} reaches 12 V, the internal current source (I _{CH}) is disabled.
6	Drain	SenseFET Drain. High-voltage power SenseFET drain connection.
7		
8		

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V _{STR}	V _{STR} Pin Voltage		700	V
V _{DS}	Drain Pin Voltage		700	V
V _{CC}	V _{CC} Pin Voltage		26	V
V _{FB}	Feedback Pin Voltage	-0.3	10.0	V
V _{IN}	V _{IN} Pin Voltage	-0.3	10.0	V
I _{DM}	Drain Current Pulsed		12	A
I _D	Continuous Switching Drain Current ⁽⁵⁾		3	A
E _{AS}	Single-Pulsed Avalanche Energy ⁽⁶⁾		230	mJ
P _D	Total Power Dissipation (T _C =25°C) ⁽⁷⁾		1.5	W
T _J	Maximum Junction Temperature		150	°C
	Operating Junction Temperature ⁽⁸⁾	-40	+125	°C
T _{STG}	Storage Temperature	-55	+150	°C
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	4.5	kV
		Charged Device Model, JESD22-C101	2.0	

Notes:

- Repetitive peak switching current when the inductive load is assumed: limited by maximum duty (D_{MAX}=0.73) and junction temperature (see Figure 4).
- L=45 mH, starting T_J=25°C.
- Infinite cooling condition (refer to the SEMI G30-88).
- Although this parameter guarantees IC operation, it does not guarantee all electrical characteristics.

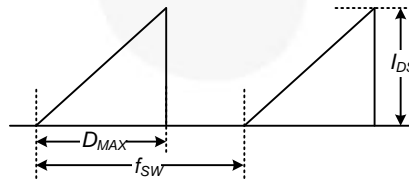


Figure 4. Repetitive Peak Switching Current

Thermal Impedance

T_A=25°C unless otherwise specified.

Symbol	Parameter	Value	Unit
θ _{JA}	Junction-to-Ambient Thermal Impedance ⁽⁹⁾	85	°C/W
ψ _{JL}	Junction-to-Lead Thermal Impedance ⁽¹⁰⁾	11	°C/W

Notes:

- JEDEC recommended environment, JESD51-2, and test board, JESD51-10, with minimum land pattern.
- Measured on drain pin #7, close to the plastic interface under R_{thja} test condition.

Electrical Characteristics

T_J = 25°C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit	
SenseFET Section							
BV _{DSS}	Drain-Source Breakdown Voltage	V _{CC} =0 V, I _D =250 μA	700			V	
I _{DSS}	Zero-Gate-Voltage Drain Current	V _{DS} =560 V, T _A =125°C			250	μA	
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} =10 V, I _D =1 A		4.00	4.75	Ω	
C _{ISS}	Input Capacitance ⁽¹¹⁾	V _{DS} =25 V, V _{GS} =0 V, f=1 MHz		315		pF	
C _{OSS}	Output Capacitance ⁽¹¹⁾	V _{DS} =25 V, V _{GS} =0 V, f=1 MHz		47		pF	
t _r	Rise Time	V _{DS} =325 V, I _D =4 A, R _G =25 Ω		34		ns	
t _f	Fall Time	V _{DS} =325 V, I _D =4 A, R _G =25 Ω		32		ns	
t _{d(on)}	Turn-On Delay	V _{DS} =325 V, I _D =4 A, R _G =25 Ω		11.2		ns	
t _{d(off)}	Turn-Off Delay	V _{DS} =325 V, I _D =4 A, R _G =25 Ω		28.2		ns	
Control Section							
f _S	Switching Frequency ⁽¹¹⁾	V _{CC} =14 V, V _{FB} =4 V	61	67	73	kHz	
Δf _S	Switching Frequency Variation ⁽¹¹⁾	-25°C < T _J < 125°C		±5	±10	%	
D _{MAX}	Maximum Duty Ratio	V _{CC} =14 V, V _{FB} =4 V	61	67	73	%	
D _{MIN}	Minimum Duty Ratio	V _{CC} =14 V, V _{FB} =0 V			0	%	
I _{FB}	Feedback Source Current	V _{FB} =0 V	65	90	115	μA	
V _{START}	UVLO Threshold Voltage	V _{FB} =0 V, V _{CC} Sweep	11	12	13	V	
V _{STOP}		After Turn-on, V _{FB} =0 V	7.0	7.5	8.0		
t _{SS}	Internal Soft-Start Time	V _{STR} =40 V, V _{CC} Sweep		15		ms	
V _{RECOMM}	Recommended V _{CC} Range		13		23	V	
Burst Mode Section							
V _{BURH}	Burst-Mode Voltage	V _{CC} =14 V, V _{FB} Sweep	0.45	0.50	0.55	V	
V _{BURL}			0.30	0.35	0.40		
Hys				150			mV
Protection Section							
I _{LIM}	Peak Drain Current Limit	di/dt=300 mA/μs	1.1	1.3	1.5	A	
V _{SD}	Shutdown Feedback Voltage	V _{CC} =14 V, V _{FB} Sweep	6.45	7.00	7.55	V	
I _{DELAY}	Shutdown Delay Current	V _{CC} =14 V, V _{FB} =4 V	1.2	2.0	2.8	μA	
t _{LEB}	Leading-Edge Blanking Time ^(10,12)			300		ns	
V _{OVP}	Over-Voltage Protection	V _{CC} Sweep	23.0	24.5	26.0	V	
V _{INH}	Line Over-Voltage Protection Threshold Voltage	V _{CC} =14 V, V _{IN} Sweep	1.885	1.950	2.015	V	
V _{INHYS}	Line Over-Voltage Protection Hysteresis	V _{CC} =14 V, V _{IN} Sweep		0.06		V	
t _{OSP}	Output-Short Protection ⁽¹¹⁾	Threshold Time	OSP Triggered when t _{ON} <t _{OSP} & V _{FB} >V _{OSP} (Lasts Longer than t _{OSP_FB})	0.7	1.0	1.3	μs
V _{OSP}		Threshold V _{FB}		1.8	2.0	2.2	V
t _{OSP_FB}		V _{FB} Blanking Time		2.0	2.5	3.0	μs
TSD	Thermal Shutdown Temperature ⁽¹¹⁾	Shutdown Temperature	125	135	145	°C	
T _{HYS}		Hysteresis		60		°C	

Continued on the following page...

Electrical Characteristics (Continued)T_J = 25°C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
Total Device Section						
I _{OP}	Operating Supply Current, (Control Part in Burst Mode)	V _{CC} =14 V, V _{FB} =0 V	0.3	0.4	0.5	mA
I _{OPS}	Operating Switching Current, (Control Part and SenseFET Part)	V _{CC} =14 V, V _{FB} =2 V		1.2	1.5	mA
I _{START}	Start Current	V _{CC} =11 V (Before V _{CC} Reaches V _{START})	85	120	155	μA
I _{CH}	Startup Charging Current	V _{CC} =V _{FB} =0 V, V _{STR} =40 V	0.7	1.0	1.3	mA
V _{STR}	Minimum V _{STR} Supply Voltage	V _{CC} =V _{FB} =0 V, V _{STR} Sweep		26		V

Notes:

11. These parameters are guaranteed; not 100% tested in production.
12. t_{LEB} includes gate turn-on time.

Typical Performance Characteristics

Characteristic graphs are normalized at $T_A=25^\circ\text{C}$.

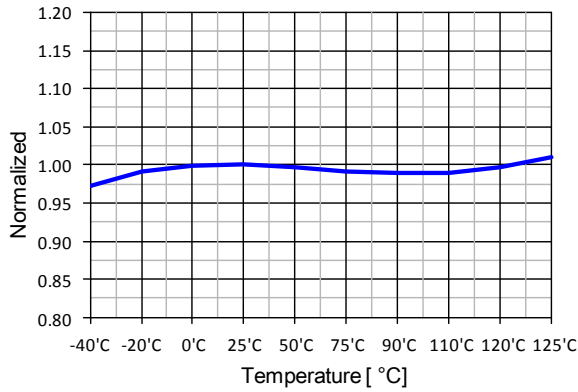


Figure 5. Operating Supply Current (I_{OP}) vs. T_A

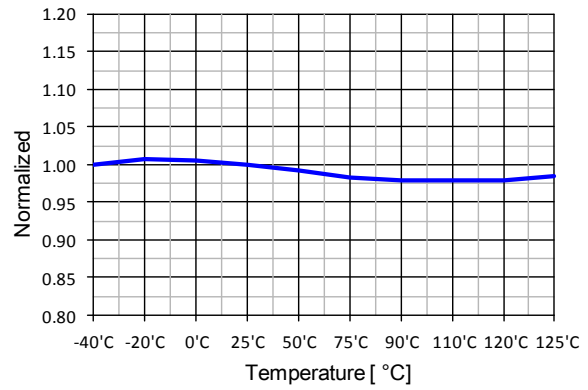


Figure 6. Operating Switching Current (I_{OPS}) vs. T_A

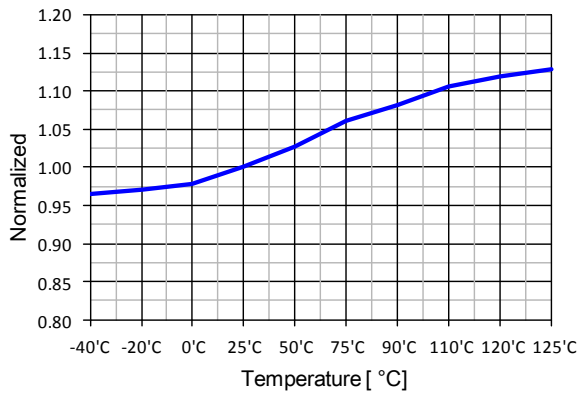


Figure 7. Startup Charging Current (I_{CH}) vs. T_A

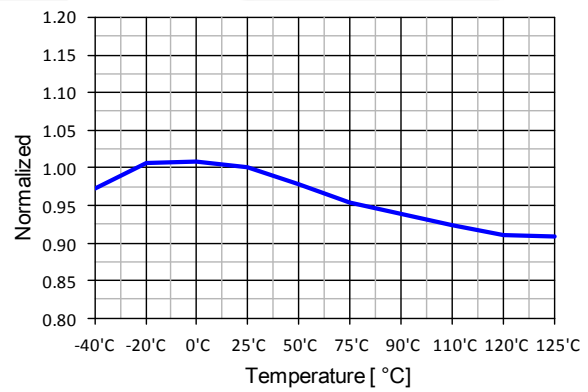


Figure 8. Peak Drain Current Limit (I_{LIM}) vs. T_A

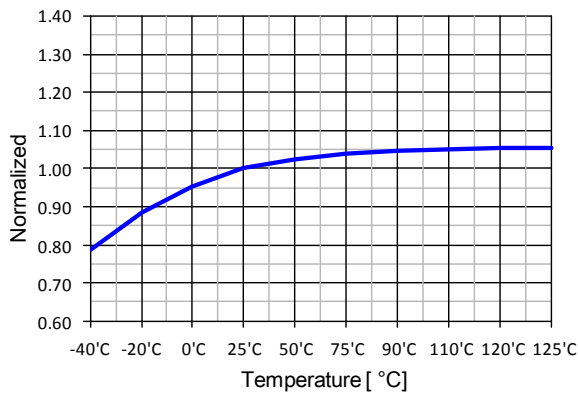


Figure 9. Feedback Source Current (I_{FB}) vs. T_A

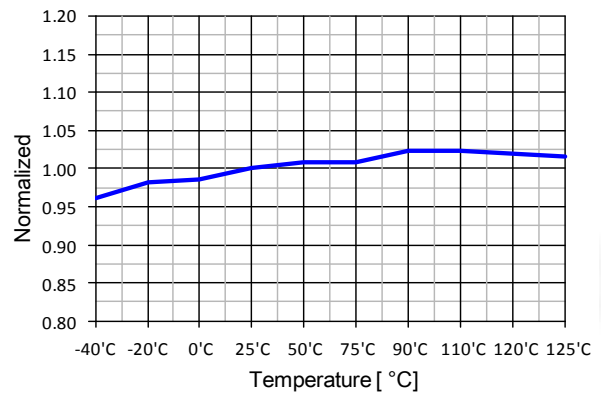


Figure 10. Shutdown Delay Current (I_{DELAY}) vs. T_A

Typical Performance Characteristics

Characteristic graphs are normalized at $T_A=25^\circ\text{C}$.

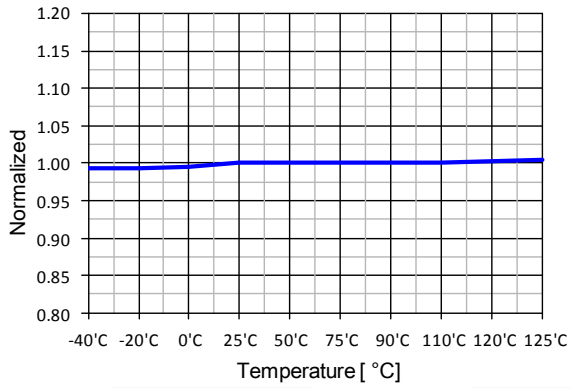


Figure 11. UVLO Threshold Voltage (V_{START}) vs. T_A

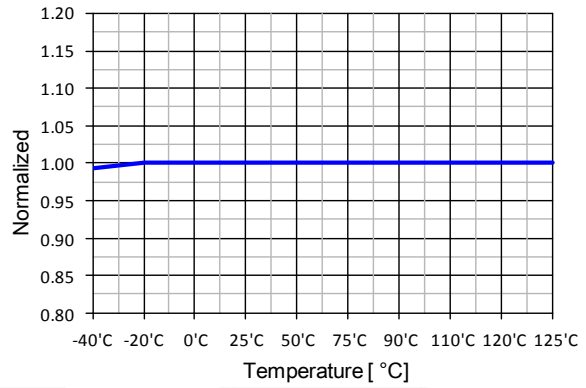


Figure 12. UVLO Threshold Voltage (V_{STOP}) vs. T_A

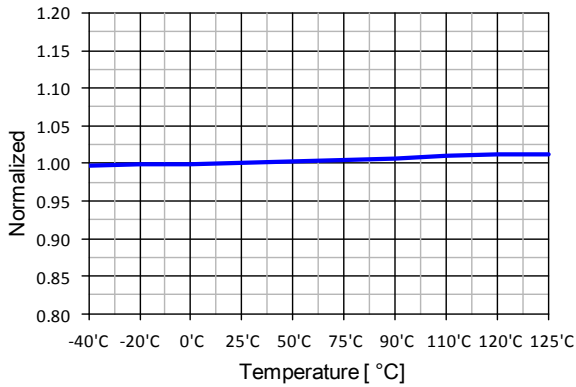


Figure 13. Shutdown Feedback Voltage (V_{SD}) vs. T_A

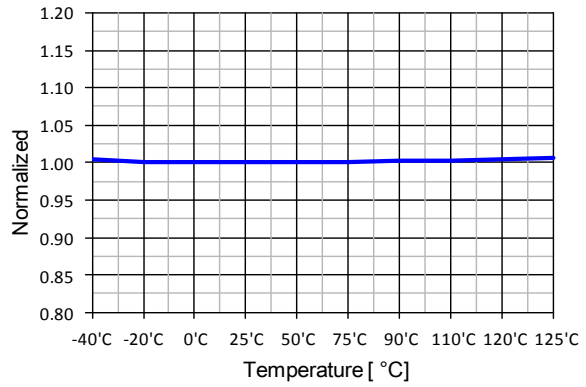


Figure 14. Over-Voltage Protection (V_{OVP}) vs. T_A

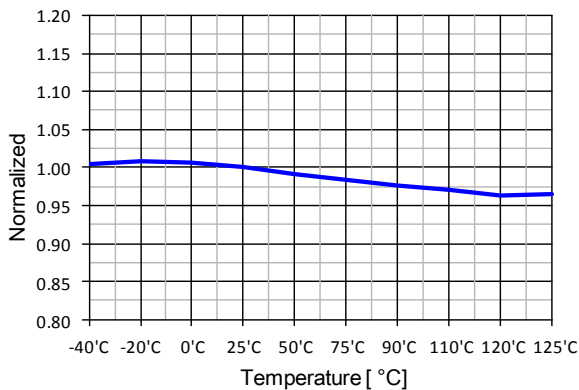


Figure 15. Switching Frequency (f_s) vs. T_A

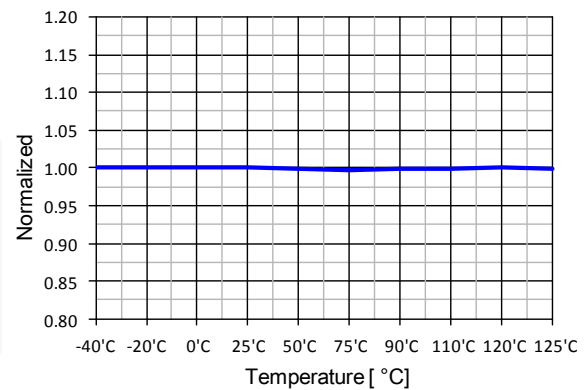


Figure 16. Maximum Duty Ratio (D_{MAX}) vs. T_A

Typical Performance Characteristics

Characteristic graphs are normalized at $T_A=25^\circ\text{C}$.

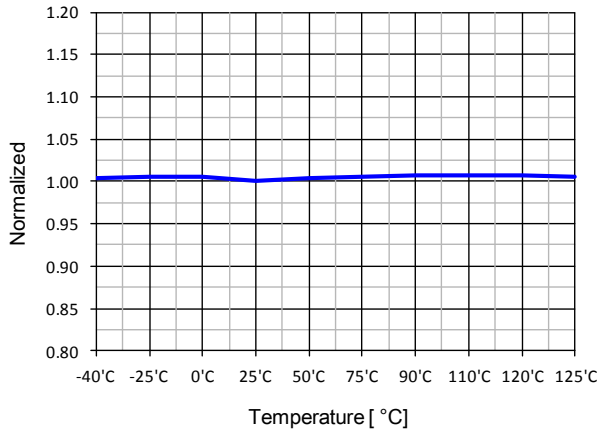


Figure 17. Line OVP (V_{INH}) vs. T_A

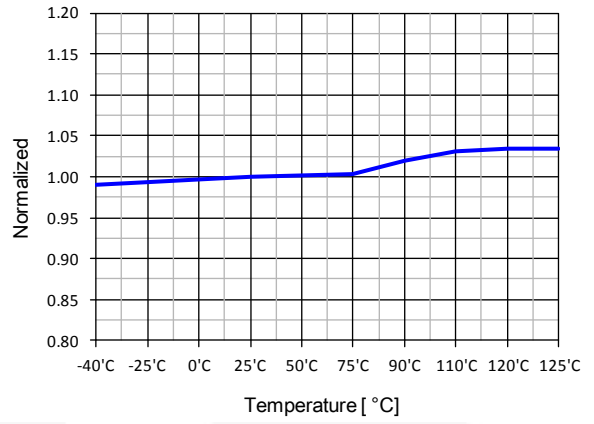


Figure 18. Hysteresis of LOVP (V_{INHYS}) vs. T_A

Functional Description

1. Startup: At startup, an internal high-voltage current source supplies the internal bias and charges the external capacitor (C_{VCC}) connected to the V_{CC} pin, as illustrated in Figure 19. When V_{CC} reaches 12 V, the FSL137MRIN begins switching and the internal high-voltage current source is disabled. Normal switching operation continues and the power is supplied from the auxiliary transformer winding unless V_{CC} goes below the stop voltage of 7.5 V.

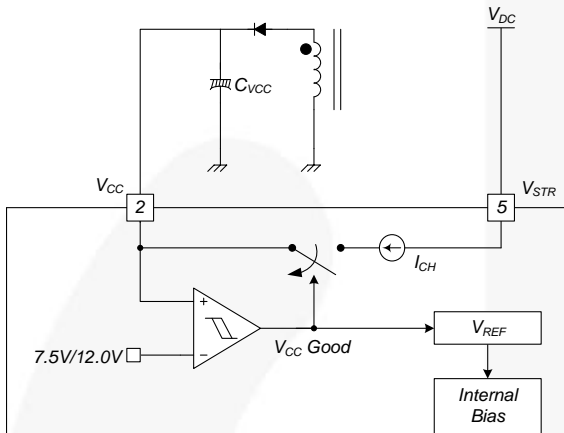


Figure 19. Startup Block

2. Soft-Start: The internal soft-start circuit increases PWM comparator inverting input voltage, together with the SenseFET current, slowly after startup. The typical soft-start time is 15 ms. The pulse width to the power switching device is progressively increased to establish the correct working conditions for the transformers, inductors, and capacitors. The voltage on the output capacitors is progressively increased to smoothly establish the required output voltage. This helps prevent transformer saturation and reduces stress on the secondary diode during startup.

3. Feedback Control: This device employs Current-Mode control, as shown in Figure 20. An opto-coupler (such as the FOD817) and shunt regulator (such as the KA431) are typically used to implement the feedback network. Comparing the feedback voltage with the voltage across the R_{SENSE} resistor makes it possible to control the switching duty cycle. When the reference pin voltage of the shunt regulator exceeds the internal reference voltage of 2.5 V, the opto-coupler LED current increases, pulling down the feedback voltage and reducing drain current. This typically occurs when the input voltage is increased or the output load is decreased.

3.1 Pulse-by-Pulse Current Limit: Because Current-Mode control is employed, the peak current through the SenseFET is limited by the inverting input of PWM comparator (V_{FB}^*), as shown in Figure 20. Assuming that the 90 μ A current source flows only through the internal resistor ($3R + R = 25 \text{ k}\Omega$), the cathode voltage of diode D2 is about 2.8 V. Since D1 is blocked when the feedback voltage (V_{FB}) exceeds 2.84 V, the maximum voltage of the cathode of D2 is clamped at this voltage. Therefore, the peak value of the current through the SenseFET is limited.

3.2 Leading-Edge Blanking (LEB): At the instant the internal SenseFET is turned on, a high-current spike usually occurs through the SenseFET, caused by primary-side capacitance and secondary-side rectifier reverse recovery. Excessive voltage across the R_{SENSE} resistor leads to incorrect feedback operation in Current-Mode PWM control. To counter this effect, the LEB circuit inhibits the PWM comparator for t_{LEB} (300 ns) after the SenseFET is turned on.

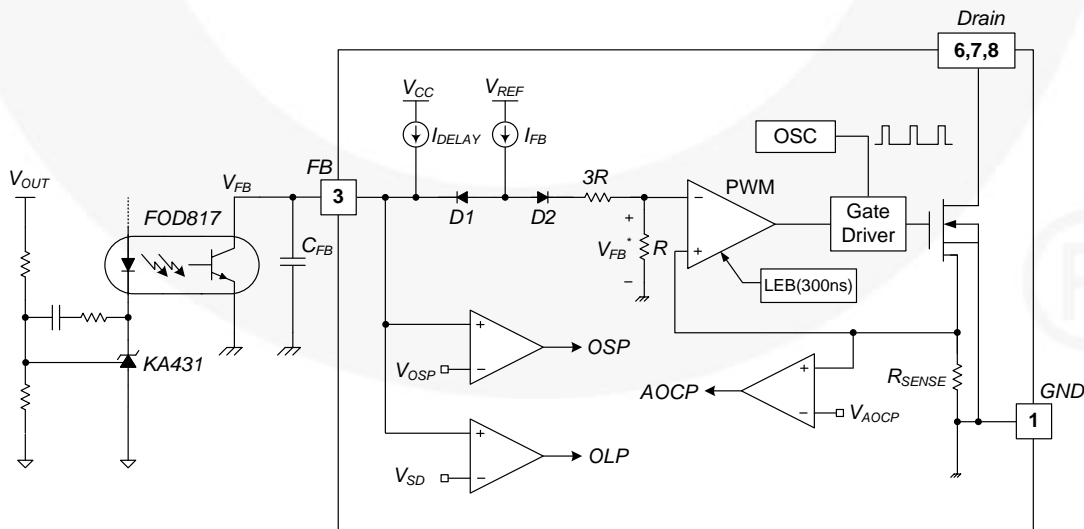


Figure 20. Pulse Width Modulation Circuit

4. Protection Circuits: The FSL137MRIN has several self-protective functions; such as Overload Protection (OLP), Abnormal Over-Current Protection (AOCP), Output-Short Protection (OSP), Over-Voltage Protection (OVP), and Thermal Shutdown (TSD). All the protections are implemented as auto-restart. Once a fault condition is detected, switching is terminated and the SenseFET remains off. This causes V_{CC} to fall. When V_{CC} falls to the Under-Voltage Lockout (UVLO) stop voltage of 7.5 V, the protection is reset and the startup circuit charges the V_{CC} capacitor. When V_{CC} reaches the start voltage of 12.0 V, normal operation resumes. If the fault condition is not removed, the SenseFET remains off and V_{CC} drops to stop voltage again. In this manner, the auto-restart can alternately enable and disable the switching of the power SenseFET until the fault condition is eliminated. Because these protection circuits are fully integrated into the IC without external components, reliability is improved without increasing cost.

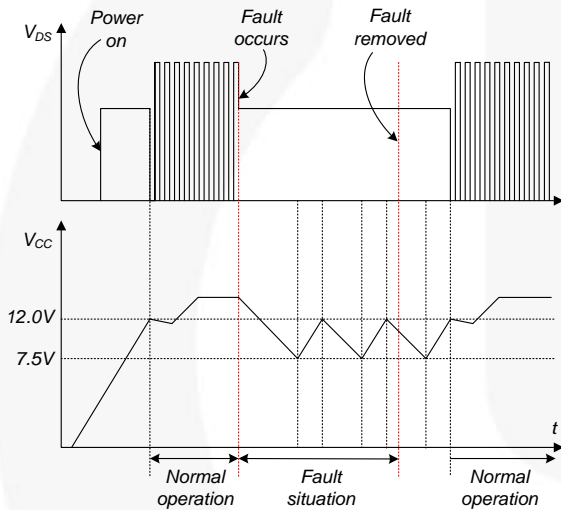


Figure 21. Auto-Restart Protection Waveforms

4.1 Overload Protection (OLP): Overload is defined as the load current exceeding its normal level due to an unexpected abnormal event. In this situation, the protection circuit should trigger to protect the SMPS. However, even when the SMPS is in normal operation, the overload protection circuit can be triggered during the load transition. To avoid this undesired operation, the overload protection circuit is designed to trigger only after a specified time to determine whether it is a transient situation or a true overload situation. Because of the pulse-by-pulse current-limit capability, the maximum peak current through the SenseFET is limited and, therefore, the maximum input power is restricted with a given input voltage. If the output consumes more than this maximum power, the output voltage (V_{OUT}) decreases below the set voltage. This reduces the current through the opto-coupler LED, which also reduces the opto-coupler transistor current, increasing the feedback voltage (V_{FB}). If V_{FB} exceeds 2.5 V, D1 is blocked and the 2.0 μ A current source starts to charge C_{FB} slowly up. In this condition, V_{FB} continues

increasing until it reaches 7.0 V, when the switching operation is terminated, as shown in Figure 22. The delay for shutdown is the time required to charge C_{FB} from 2.5 V to 7.0 V with 2.0 μ A. A 25 ~ 50 ms delay is typical for most applications. This protection is implemented as auto-restart.

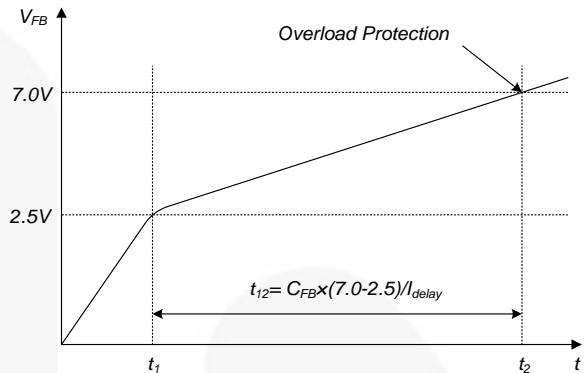


Figure 22. Overload Protection

4.2 Abnormal Over-Current Protection (AOCP): When the secondary rectifier diodes or the transformer pins are shorted, a steep current with extremely high di/dt can flow through the SenseFET during the minimum turn-on time. Even though the FSL137MRIN has overload protection, it is not enough to protect the FSL137MRIN in that abnormal case; due to the severe current stress imposed on the SenseFET until OLP is triggered. The internal AOCP circuit is shown in Figure 23. When the gate turn-on signal is applied to the power SenseFET, the AOCP block is enabled and monitors the current through the sensing resistor. The voltage across the resistor is compared with a preset AOCP level. If the sensing-resistor voltage is greater than the AOCP level, the set signal is applied to the S-R latch, resulting in the shutdown of the SMPS.

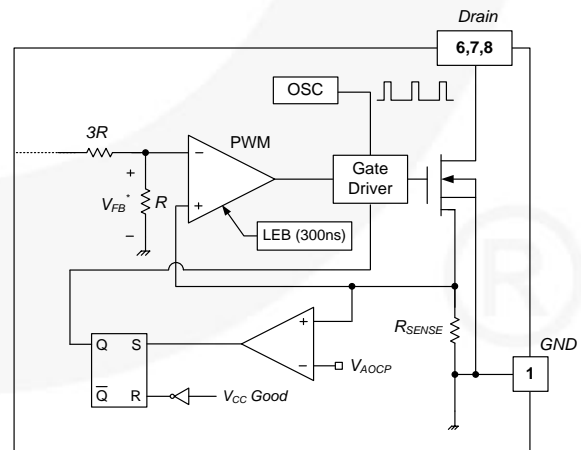


Figure 23. Abnormal Over-Current Protection

4.3. Output-Short Protection (OSP): If the output is shorted, steep current with extremely high di/dt can flow through the SenseFET during the minimum turn-on time. Such a steep current creates high-voltage stress on the drain of the SenseFET when turned off. To protect the device from this abnormal condition, OSP is included. It is comprised of detecting V_{FB} and SenseFET turn-on time. When the V_{FB} is higher than 2.0 V and the SenseFET turn-on time is lower than 1.0 μ s, this condition is recognized as an abnormal error and PWM switching shuts down until V_{CC} reaches V_{START} again. An abnormal condition output short is shown in Figure 24.

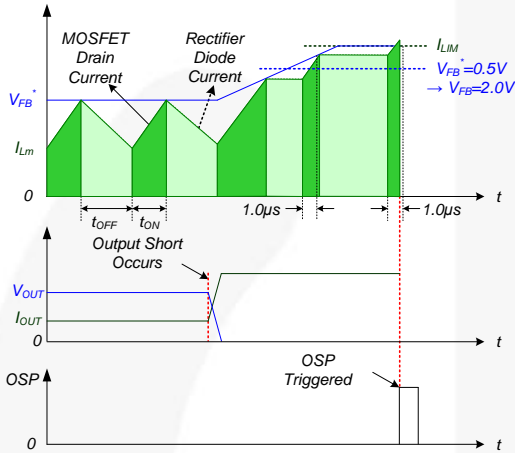


Figure 24. Output-Short Protection

4.4 Over-Voltage Protection (OVP): If the secondary-side feedback circuit malfunctions or a solder defect causes an opening in the feedback path; the current through the opto-coupler transistor becomes almost zero. Then V_{FB} climbs up in a similar manner to overload situation, forcing the preset maximum current to be supplied to the SMPS until the overload protection is triggered. Because more energy than required is provided to the output, the output voltage may exceed the rated voltage before the overload protection is triggered, resulting in the breakdown of the devices in the secondary side. To prevent this situation, an OVP circuit is employed. In general, the V_{CC} is proportional to the output voltage and the FSL137MRIN uses V_{CC} instead of directly monitoring the output voltage. If V_{CC} exceeds 24.5 V, an OVP circuit is triggered, resulting in the termination of the switching operation. To avoid undesired activation of OVP during normal operation, V_{CC} should be designed below 24.5 V.

4.5 Thermal Shutdown (TSD): The SenseFET and the control IC on a die in one package makes it easier for the control IC to detect the temperature of the SenseFET. If the temperature exceeds $\sim 135^{\circ}\text{C}$, the thermal shutdown is triggered and stops operation. The FSL137MRIN operates in Auto-Restart Mode until the temperature decreases to around 75°C , when normal operation resumes.

4.6 Line Over-Voltage Protection (LOVP): If the line input voltage is increased to an undesirable level, high line input voltage creates high-voltage stress on the entire system. To protect from this abnormal condition, LOVP is included. It is comprised of detecting V_{IN} using divided resistors. When V_{IN} is higher than 1.95 V, this condition is recognized as an abnormal error and PWM switching shuts down until V_{IN} decreases to around 1.89 V (60 mV hysteresis).

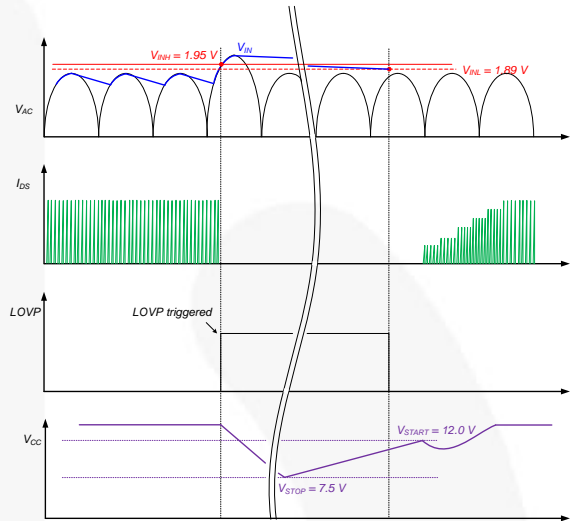


Figure 25. Line Over-Voltage Protection

Unlike previous FPS families, FSL137MRIN's V_{IN} pin can detect the AC line over-voltage protection function. When line input voltage exceeds pre-determined level at the V_{IN} pin, the controller initiates a fault signal and shuts down PWM output. To prevent erroneous activation of LOVP, the LOVP function is triggered when line over-voltage lasts more than specific time. Another important feature of LOVP function is auto-recovery. The controller continuously monitors line input voltage even under fault condition and turns PWM output on when over-voltage condition disappears. Equation (1) calculates the level of input over voltage to RMS value:

$$V_{IN_ovp} = 1.95 \times \left(\frac{(R1 + R2)}{R1} \right) \quad (1)$$

The resistance of divided resistor can be adjusted as necessary. Small resistance can bring relatively large stand-by power consumption at light-load condition. To avoid this situation, a several M Ω resistor is recommended. For stable operation, a several M Ω resistor should accompany a capacitor with hundreds of pF capacitance between the V_{IN} pin and GND.

5. Soft Burst Mode: To minimize power dissipation in Standby Mode, the FSL137MRIN enters Burst-Mode operation. As the load decreases, the feedback voltage decreases. As shown in Figure 26, the device automatically enters Burst Mode when the feedback voltage drops below V_{BURL} (350 mV). At this point, switching stops and the output voltages start to drop at a rate dependent on standby current load. This causes the feedback voltage to rise. Once it passes V_{BURH} (500 mV), switching resumes. The feedback voltage then falls and the process repeats. Burst Mode alternately enables and disables SenseFET switching, reducing switching loss in Standby Mode.

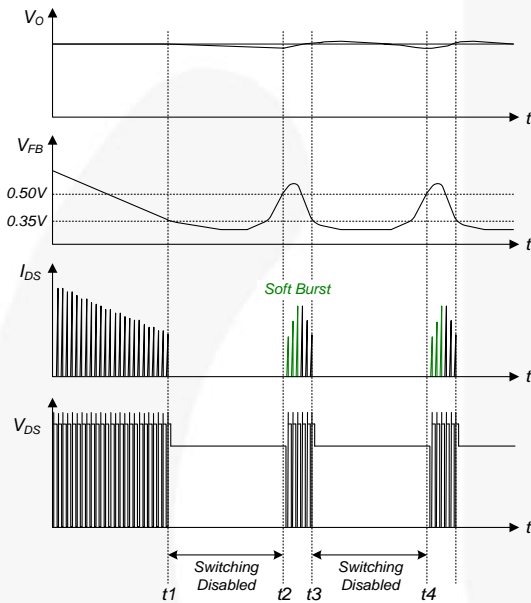


Figure 26. Burst-Mode Operation

6. Random Frequency Fluctuation (RFF): Fluctuating switching frequency of an SMPS can reduce EMI by spreading the energy over a wide frequency range. The amount of EMI reduction is directly related to the switching frequency variation, which is limited internally. The switching frequency is determined randomly by external feedback voltage and an internal free-running oscillator at every switching instant. RFF effectively scatters EMI noise around typical switching frequency (67 kHz) and can reduce the cost of the input filter included to meet the EMI requirements (e.g. EN55022).

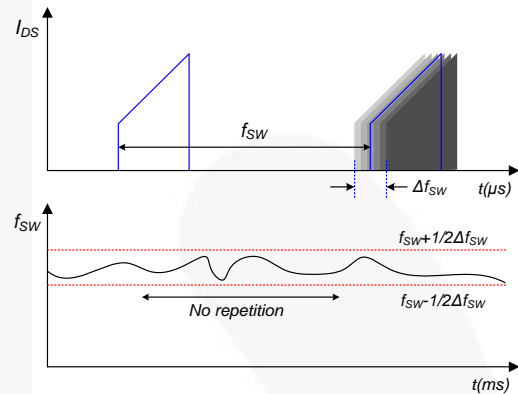
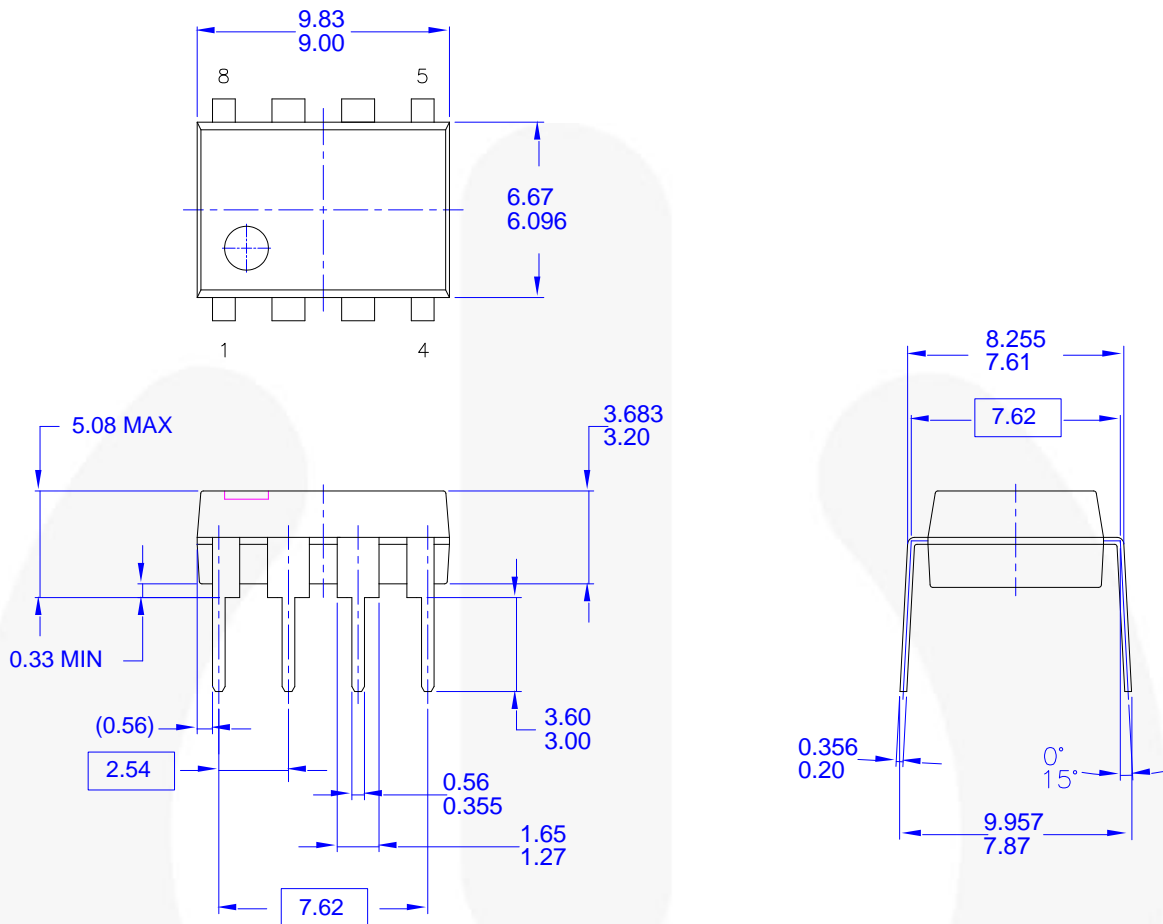


Figure 27. Random Frequency Fluctuation

Package Dimensions



NOTES: UNLESS OTHERWISE SPECIFIED

- A) THIS PACKAGE CONFORMS TO JEDEC MS-001 VARIATION BA
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D) DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994
- E) DRAWING FILENAME AND REVISION: MKT-N08FREV2.

Figure 28. 8-Lead, MDIP, JEDEC MS-001, .300" Wide





Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:
<http://www.fairchildsemi.com/dwg/N0/N08F.pdf>.



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

- | | | | |
|---|--|---|---|
| AccuPower™ | F-PFS™ |  | Sync-Lock™ |
| AX-CAP®* | FRFET® | PowerTrench® | SYSTEM GENERAL® |
| BitSiC™ | Global Power Resource™ | PowerXS™ | TinyBoost® |
| Build it Now™ | GreenBridge™ | Programmable Active Droop™ | TinyBuck® |
| CorePLUS™ | Green FPS™ | QFET® | TinyCalc™ |
| CorePOWER™ | Green FPS™ e-Series™ | QS™ | TinyLogic® |
| CROSSVOLT™ | Gmax™ | Quiet Series™ | TINYOPTO™ |
| CTL™ | GTO™ | RapidConfigure™ | TinyPower™ |
| Current Transfer Logic™ | IntelliMAX™ |  | TinyPWM™ |
| DEUXPEED® | ISOPLANAR™ | Saving our world, 1mW/W/kW at a time™ | TinyWire™ |
| Dual Cool™ | Making Small Speakers Sound Louder and Better™ | SignalWise™ | TranSiC™ |
| EcoSPARK® | MegaBuck™ | SmartMax™ | TriFault Detect™ |
| EfficientMax™ | MICROCOUPLER™ | SMART START™ | TRUECURRENT®* |
| ESBC™ | MicroFET™ | Solutions for Your Success™ | μSerDes™ |
|  | MicroPak™ | SPM® |  |
| Fairchild® | MicroPak2™ | STEALTH™ | UHC® |
| Fairchild Semiconductor® | MillerDrive™ | SuperFET® | Ultra FRFET™ |
| FACT Quiet Series™ | MotionMax™ | SuperSOT™-3 | UniFET™ |
| FACT® | mWSaver® | SuperSOT™-6 | VCX™ |
| FAST® | OptoHiT™ | SuperSOT™-8 | VisualMax™ |
| FastvCore™ | OPTOLOGIC® | SupreMOS® | VoltagePlus™ |
| FETBench™ | OPTOPLANAR® | SyncFET™ | XTM |
| FPS™ | | | |

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 166

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com
Order Literature: <http://www.onsemi.com/orderlit>
For additional information, please contact your local
Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[ON Semiconductor:](#)

[FSL137MRIN](#)



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.